



DTNN143Z

DUAL TRANSISTOR

COMPOUND TRANSISTORS

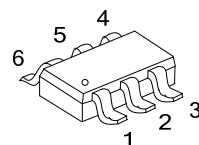
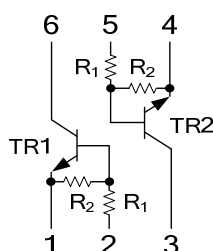
DESCRIPTION

The UTC **DTNN143Z** is an NPN epitaxial transistor; it uses UTC's advanced technology to provide the customers with low collector-emitter saturation voltage, etc.

FEATURES

- * Two DTC143Z chips in a SOT-363 package
- * Low collector-emitter saturation voltage
- * With built-in bias resistors
- * Simplify circuit design
- * Silicon epitaxial type.
- * The internal two transistor elements are independent.

SYMBOL



SOT-363

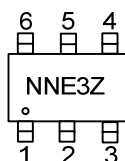
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment						Packing
Lead Free	Halogen Free		1	2	3	4	5	6	
DTNN143ZL-AL6-R	DTNN143ZG-AL6-R	SOT-363	G1	I1	O2	G2	I2	O1	Tape Reel

Note: Pin Assignment: G: GND I: Input O: Output

DTNN143ZG-AL6-R		(1) Packing Type	(1) R: Tape Reel
		(2) Package Type	(2) AL6: SOT-363
		(3) Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{CC}	50	V
Input Voltage	V_{IN}	-5 ~ +30	V
Output Current	I_{OUT}	100	mA
	$I_C (MAX)$	100	mA
Power Dissipation	P_D	150	mW
Junction Temperature	T_J	+150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55 ~ +150	$^{\circ}\text{C}$

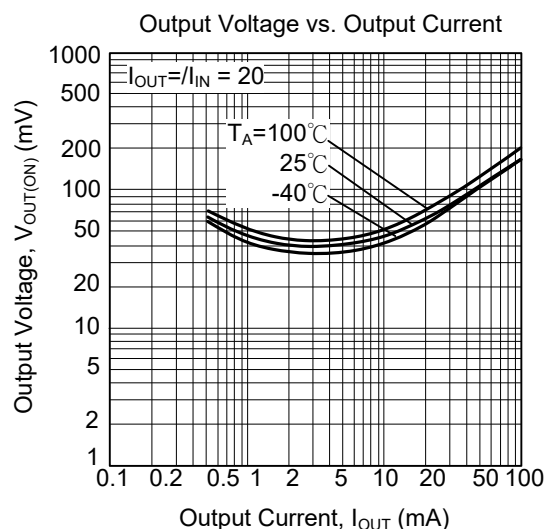
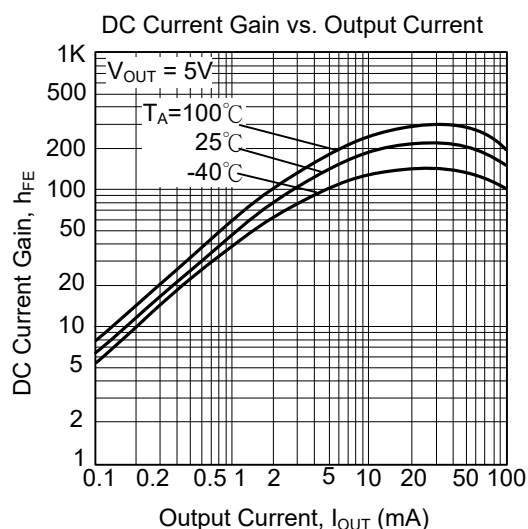
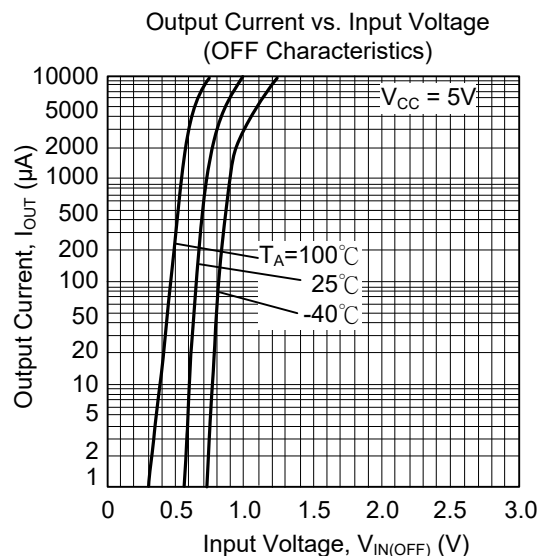
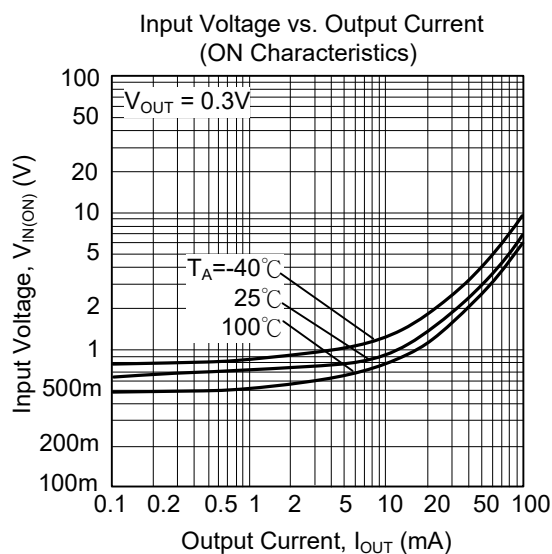
Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	$V_{IN(OFF)}$	$V_{CC}=5V, I_{OUT}=100\mu A$			0.5	V
	$V_{IN(ON)}$	$V_{OUT}=0.3V, I_{OUT}=5mA$	1.3			V
Output Voltage	$V_{OUT(ON)}$	$I_{OUT}/I_{IN}=5mA/0.25mA$		0.1	0.3	V
Input Current	I_{IN}	$V_{IN}=5V$			1.8	mA
Output Current	$I_{O(OFF)}$	$V_{CC}=50V, V_{IN}=0V$			0.5	μA
DC Current Gain	h_{FE}	$V_{OUT}=5V, I_{OUT}=10mA$	80			
Input Resistance	R_1		3.29	4.7	6.11	K Ω
Resistance Ratio	R_2 / R_1		8	10	12	
Transition Frequency	f_T	$V_{CE}=10V, I_E=-5mA, f=100MHz$ (Note)		250		MHz

Note: Transition frequency of the device.

TYPICAL CHARACTERISTICS



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